

MiniSKiiP[®] 3 Dual

Half-Bridge

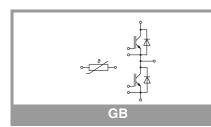
SKiiP 39GB12E4V1

Features*

- Trench 4 IGBT's
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized file no. E63532

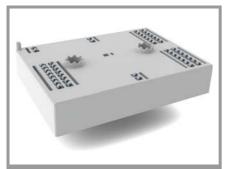
Remarks

- Case temp. limited to T_C = 125°C max. (for baseplateless modules T_C = T_S)
- product rel. results valid for Tj≤150 (recomm. Top = -40 ... +150°C)



Absolute	Maximum Rating	6			
Symbol	Conditions		Values	Unit	
Inverter -	$\begin{array}{c c c c c c c c } & IGBT & & & & & & & & & & & & & & & & & & &$				
V _{CES}	T _j = 25 °C		1200	V	
Ic	λ _{paste} =0.8 W/(mK)	T _s = 25 °C	389	А	
	T _j = 175 °C	T _s = 70 °C	313	А	
I _C	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	582	A	
	T _j = 175 °C	T _s = 70 °C	474	А	
I _{Cnom}			400	А	
I _{CRM}			1200	А	
V _{GES}			-20 20	V	
t _{psc}	$V_{GE} \le 15 \text{ V}$	T _j = 150 °C	10	μs	
Tj			-40 175	°C	
Inverse -	Diode				
IF	λ _{paste} =0.8 W/(mK)	0.8 W/(mK) $T_s = 25 ^{\circ}C$ 363	363	А	
		T _s = 70 °C	287	Α	
I _F	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	422	А	
			335	Α	
I _{FRM}			800	Α	
I _{FSM}	10 ms, sin 180°, T _j	= 150 °C	1980	А	
Tj			-40 175	°C	
Module	•				
I _{t(RMS)}	T _{terminal} = 80 °C, 20	A per spring	280	А	
T _{stq}	module without TIN	Λ	-40 125	°C	
V _{isol}	AC sinus 50 Hz, t =	1 min	2500	V	

Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT					
V _{CE(sat)}	$I_{\rm C} = 400 {\rm A}$	T _j = 25 °C		1.80	2.05	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.20	2.40	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V	T _j = 25 °C		2.5	2.9	mΩ
	chiplevel	T _j = 150 °C		3.8	4.0	mΩ
V _{GE(th)}	$V_{GE} = V_{CE}, I_C = 15.2$	2 mA	5	5.8	6.5	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = 12$	00 V, T _j = 25 °C			4.0	mA
C _{ies}	1 Voc - 25 V	f = 1 MHz		24.60		nF
Coes		f = 1 MHz		1.62		nF
C _{res}	VGE - V V	f = 1 MHz		1.38		nF
Q _G	V _{GE} = - 8 V+ 15 V	V _{GE} = - 8 V+ 15 V				nC
R _{Gint}	T _j = 25 °C			1.9		Ω
t _{d(on)}		T _j = 150 °C		183		ns
t _r	$I_{\rm C} = 400 {\rm A}$	T _j = 150 °C		62		ns
Eon	$R_{G \text{ on}} = 1.5 \Omega$ $R_{G \text{ off}} = 1.5 \Omega$	T _j = 150 °C		20.8		mJ
t _{d(off)}	$di/dt_{on} = 6940 \text{ A}/\mu \text{s}$	T _j = 150 °C		520		ns
t _f	di/dt _{off} = 2930 A/µs	T _j = 150 °C		118		ns
E _{off}	V _{GE} = +15/-15 V L _s = 25 nH	T _j = 150 °C		49.7		mJ
R _{th(j-s)}	per IGBT, $\lambda_{paste}=0.8$	3 W/(mK)		0.16		K/W
R _{th(j-s)}	per IGBT, λ _{paste} =2.5	5 W/(mK)		0.08		K/W



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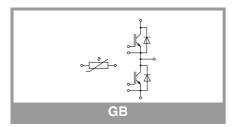
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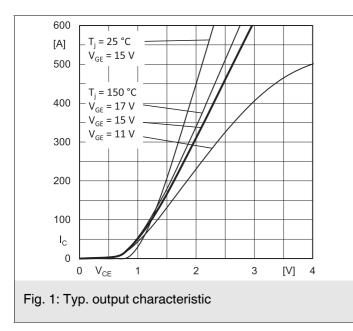
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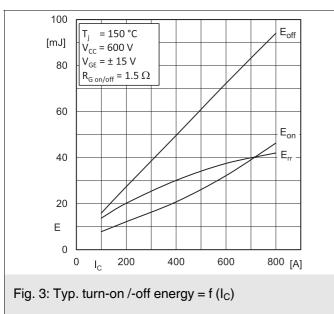
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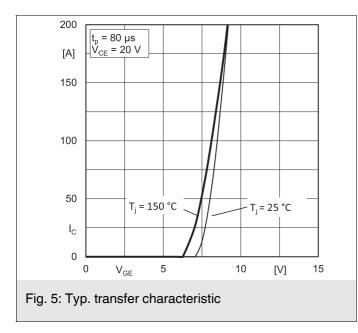
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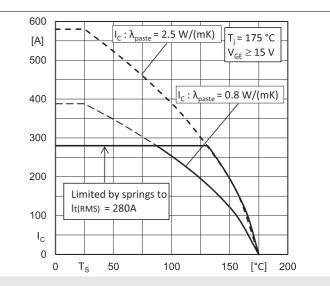
Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 400 A	T _j = 25 °C		2.20	2.52	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.15	2.47	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
	Chiplevel	T _j = 150 °C		0.90	1.10	V
r _F	chiplevel	T _j = 25 °C		2.3	2.6	mΩ
	Chiplevel	T _j = 150 °C		3.1	3.4	mΩ mΩ A μC
I _{RRM}	di/dt _{off} = 6840 A/µs V _{GE} = -15 V	T _j = 150 °C		425		Α
Q _{rr}		T _j = 150 °C		63.2		μC
E _{rr}	$V_{CC} = 600 V$	T _j = 150 °C		30.2		mJ
R _{th(j-s)}	per Diode, $\lambda_{paste}=0$.	8 W/(mK)		0.19		K/W
R _{th(j-s)}	per Diode, λ_{paste} =2.5 W/(mK)			0.15		K/W
Module						
L _{CE}				15		nH
Ms	to heat sink		2		2.5	Nm
w				76		g
Temperat	ture Sensor					
R ₁₀₀	T _c =100°C (R ₂₅ =5 k	Ω)		493 ± 5%		Ω
B _{25/85}	R _(T) =R ₂₅ *exp[B _{25/85}	*(1/T-1/298)], T[K]		3420		K

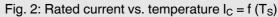


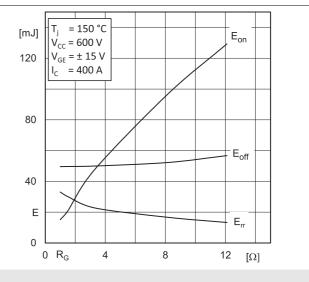


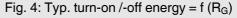


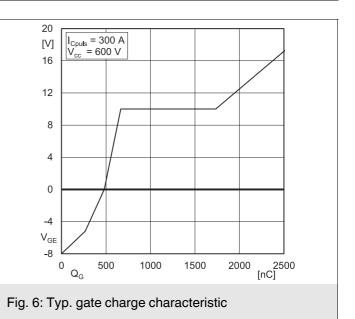


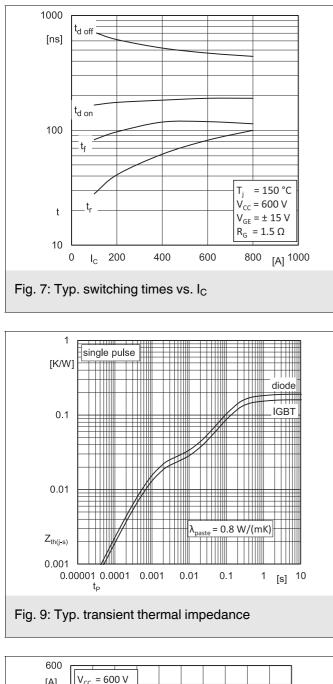


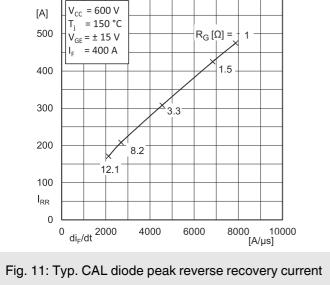


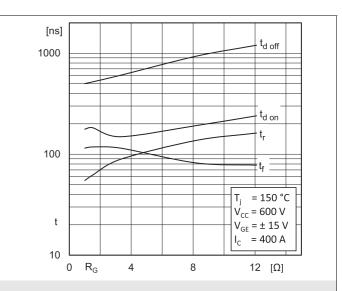


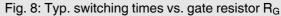


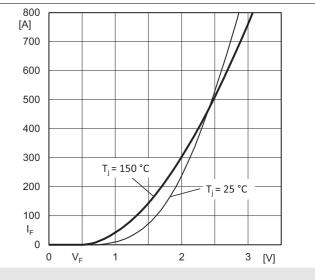


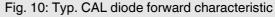


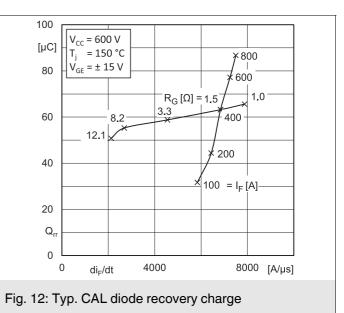








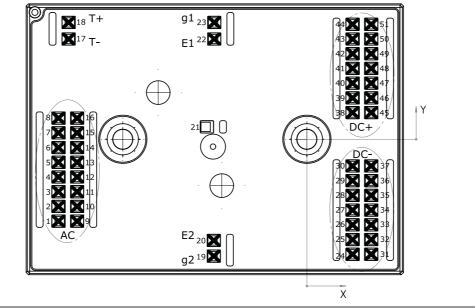




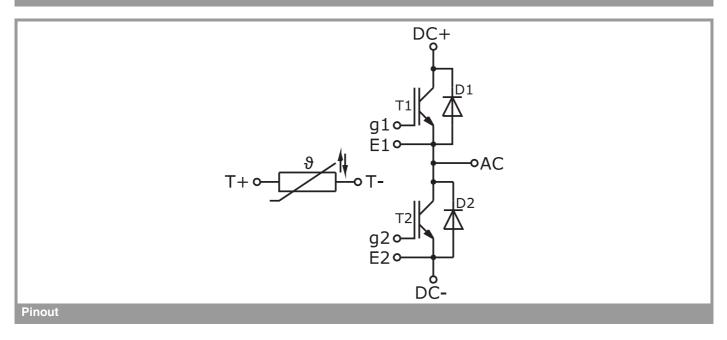
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	Pin out										
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	-53,98	-17,80	AC	18	-51,78		T+	35	13,98	-12,20	DC-
2	-53,98	-14,60	AC	19	-20,23	-25,40	g2	36	13,98	-9,00	DC-
3	-53,98	-11,40	AC	20	-20,23	-22,00	E2	37	13,98	-5,80	DC-
4	-53,98	-8,20	AC	21	-21,73	2,70		38	9,93	5,80	DC+
5	-53,98		AC	22	-20,13	21,80	E1	39	9,93	9,00	DC+
6	-53,98	-1,80	AC	23	-20,13	25,40	g1	40	9,93	12,20	DC+
7	-53,98	1,40	AC	24	9,93	-25,00	DC-	41	9,93	15,40	DC+
8	-53,98	4,60	AC	25	9,93	-21,80	DC-	42	9,93	18,60	DC+
9	-49,93	-17,80	AC	26	9,93	-18,60	DC-	43	9,93	21,80	DC+
10	-49,93	-14,60	AC	27	9,93	-15,40	DC-	44	9,93	25,00	DC+
11	-49,93	-11,40	AC	28	9,93	-12,20	DC-	45	13,98	5,80	DC+
12	-49,93	-8,20	AC	29	9,93	-9,00	DC-	46	13,98	9,00	DC+
13	-49,93	-5,00	AC	30	9,93	-5,80	DC-	47	13,98	12,20	DC+
14	-49,93	-1,80	AC	31	13,98	-25,00	DC-	48	13,98	15,40	DC+
15	-49,93	1,40	AC	32	13,98	-21,80	DC-	49	13,98	18,60	DC+
16	-49,93	4,60	AC	33	13,98	-18,60	DC-	50	13,98	21,80	DC+
17	-51,78	21,80	Т-	34	13,98	-15,40	DC-	51	13,98	25,00	DC+

all values in [mm]



Pinout and Dimensions



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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